## 800-2500MHz MMIC WIDEBAND AMPLIFIER

# Medium Power, 22dB Gain, Wide Dynamic Range

#### **DESCRIPTION**

The ZAMP002 is an low current high performance RF amplifier designed for L band and IF applications. Although the ZAMP002 has been designed primarily for DBS applications the ZAMP002 is capable of extending to frequencies of 2.5GHz so it has a good fit with various applications. An additional benefit of the ZAMP002 is it's rising gain characteristic, this has been designed to counteract the gain losses found at the higher frequencies. The ZAMP002 has been optimized to an input impedance of 50ohms while the output impedance has been designed for optimum match to an impedance of 75ohms. Packaged in a small SC70-6 with the minimum number of external bias components required it is the ideal solution for space and current limited applications.



- · L and IF frequency band
- · Low noise
- Low current consumption 21mA typical
- · Gain 22dB typical
- Rising gain across band
- IP3 22dBm @ 1GHz
- 4.5 to 5.5V supply voltage
- SC70-6 SMD package

#### **APPLICATIONS**

- Satellite LNB receivers
- RF buffers tuners
- SMR (Special Mobile Radio)
- RLAN/WLAN
- General purpose



SC70-6

### **CONNECTION DIAGRAM**

GND 1 6 OUTPUT
GND 2 5 GND
INPUT 3 4 V<sub>CC</sub>

### **ORDERING INFORMATION**

DEVICE	REEL SIZE (inches)	QUANTITY PER REEL	DEVICE MARKI NG
ZAMP002H6TA	7″	3000 units	ZB02
ZAMP002H6TC	13"	10000 units	ZB02

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ZETEX SEMICONDUCTORS

## **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage 7V
Supply Current 30mA
Operating Temperature -40 to 85°C
Storage Temperature -50 to 125°C

### **ELECTRICAL CHARACTERISTICS**

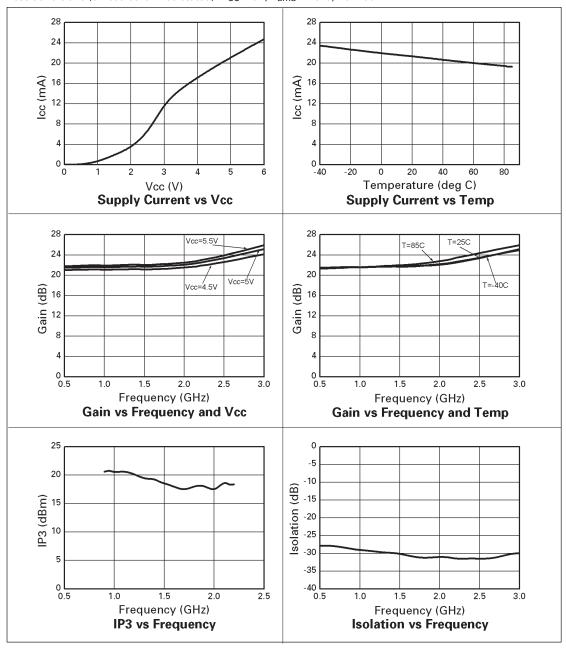
Test Conditions (unless otherwise stated):  $V_{CC}$  = 5V,  $T_{amb}$  = 25°C,  $Z_{o}$  = 50 $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNITS
F <sub>O</sub>	Operating Frequency		800		2500	MHz
V <sub>CC</sub>	Supply Voltage		4.5	5	5.5	V
I <sub>CC</sub>	Supply Current			21	24	mA
Gp	Power Gain	F = 950 MHz	21	22		dB
		F = 1550 MHz		22		dB
		F = 2150 MHz		23	25	dB
NF	Noise Figure	F = 950 MHz		6		dB
		F = 1550 MHz		6.5		dB
		F = 2150 MHz		7		dB
IP3	3rd Order Intercept Point	F = 950 MHz	18	22		dBm
		F = 2150 MHz		17		dBm
P1dB	1dB Gain Compression	F = 950 to 2150 MHz		7		dBm
RL <sub>IN</sub>	Input Return Loss	F = 950 MHz		16		dB
		F = 2150 MHz		17		dB
RLOUT	Output Return Loss	F = 950 MHz		10		dB
		F = 2150 MHz		9		dB
Risol	Reverse Isolation	F = 950 MHz		30		dB
		F = 2150 MHz		33		dB



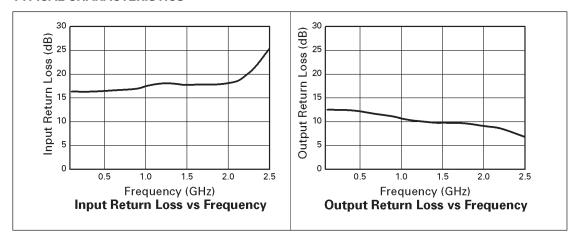
### **TYPICAL CHARACTERISTICS**

Test Conditions (unless otherwise stated):  $V_{CC} = 5V$ ,  $T_{amb} = 25$ °C,  $Z_{O} = 50\Omega$ .



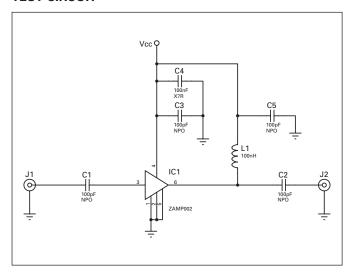


### **TYPICAL CHARACTERISTICS**





### **TEST CIRCUIT**

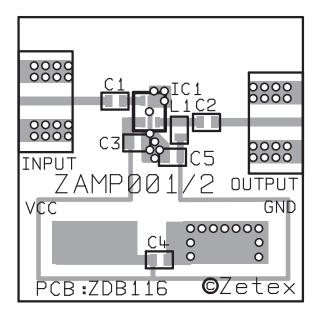


## **CIRCUIT COMPONENTS LIST**

Circuit Ref.	Description	Value	Туре
C1,C2,C3, C5	Chip ceramic capacitor	100 pF	Murata GRH708 series, size 0805
C4	Chip ceramic capacitor	100 nF	X7R, size 0805
L1	Chip inductor	100 nH	Murata LQW18ANR10G00D, size 0805
IC1	ZAMP002		Wideband Amplifier, SC70-6



### **TEST CIRCUIT LAYOUT**



#### **APPLICATION NOTES**

The ZAMP002 is a wideband RFIC amplifier designed for use primarily in DBS applications. The amplifier is designed to provide a 50 Ohm input and 75 Ohm output and thus requires no additional matching components. The input and output signal connections each require a DC blocking capacitor (C1 and C2). A suitable value for these capacitors is 100pF for the 950MHz to 2150MHz frequency range. For other frequency ranges the value of the capacitor should be such that its reactance at the lowest operating frequency is small when compared to 50 ohms (or 75 Ohms for the output). Supply de-coupling is also recommended and should take the form of a suitable 100pF capacitor, C3, for the 950MHz to 2150MHz frequency range. The 100pF capacitor should be mounted as close to the Vcc pin of the amplifier as is physically possible. An additional low frequency de-coupling capacitor, C4, with a value of 100nF is also advised. The ZAMP002 requires a RF choke inductor, L1, providing DC bias to the output line. A value of 100nH is recommended for the 950 MHz to 2150MHz frequency range.

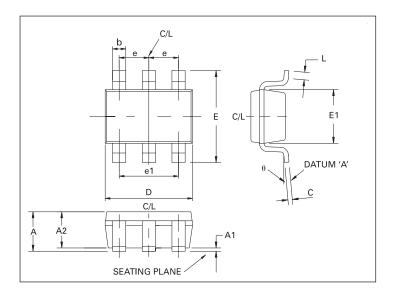
An example layout for a test board for the ZAMP series can be seen above. This was designed for an FR4 board 1 x 1 inch, 0.016 inch thick with a copper thickness of 35 microns. Edge mounted SMA connectors were used for the RF signals.



Notes

ZETEX SEMICONDUCTORS

### **PACKAGE DIMENSIONS SC706**



### **PACKAGE DIMENSIONS**

DIM	MILLIMETRES		5.11.4	MILLIMETRES		
	MIN	MAX	DIM	MIN	MAX	
Α	_	1.00	Е	2.10 BSC		
A1	_	0.10	E1	1.25	1.35	
A2	0.70	0.90	е	0.65 BSC		
b	0.15	0.30	e1	1.30 BSC		
С	0.08	0.25	L	0.26	0.46	
D	2.00 BSC		θ	0°	8°	

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Europe		Americas	Asia Pacific
Zetex plc	Zetex GmbH	Zetex Inc	Zetex (Asia) Ltd
Fields New Road	Streitfeldstraße 19	700 Veterans Memorial Hwy	3701-04 Metroplaza Tower 1
Chadderton	D-81673 München	Hauppauge, NY 11788	Hing Fong Road
Oldham, OL9 8NP			Kwai Fong
United Kingdom	Germany	USA	Hong Kong
Telephone (44) 161 622 4444	Telefon: (49) 89 45 49 49 0	Telephone: (1) 631 360 2222	Telephone: (852) 26100 611
Fax: (44) 161 622 4446	Fax: (49) 89 45 49 49 49	Fax: (1) 631 360 8222	Fax: (852) 24250 494
hq@zetex.com	europe.sales@zetex.com	usa.sales@zetex.com	asia.sales@zetex.com

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